

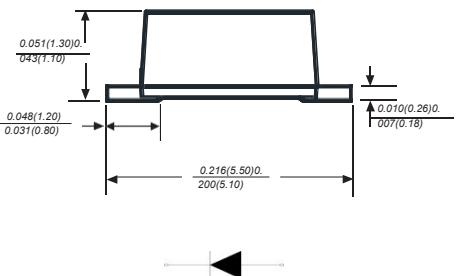
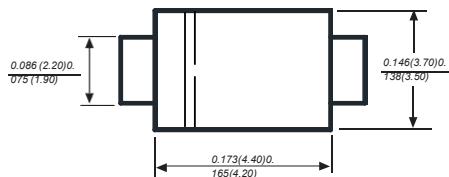
## SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

### Features

- ◆ Metal silicon junction, majority carrier conduction For surface mounted applications
- ◆ Low power loss,high efficiency
- ◆ High forward surge current capability
- ◆ For use in low voltage,high frequency inverters, free wheeling, and polarity protection applications

**SMBF**

 **RoHS  
COMPLIANT**



Dimensions in inches and (millimeters)

### Mechanical Data

Case : JEDEC SMBF molded plastic body

Terminals : Solderable per MIL-STD-750, Method 2026

Polarity : Polarity symbol marking on body Mounting

Position : Any

Weight : 0.002 ounce, 0.057 grams

### Maximum Ratings And Electrical Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz,resistive or inductive load,for capacitive load current derate by 20%.

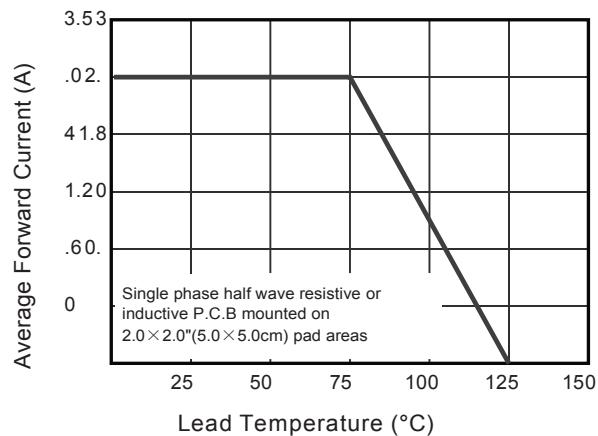
Parameter	SYMBOLS	SS32BF	SS33BF	SS34BF	SS35BF	SS36BF	SS38BF	SS310BF	SS315BF	SS320BF	UNITS				
Marking Code		RCD SS32BF	RCD SS33BF	RCD SS34BF	RCD SS35BF	RCD SS36BF	RCD SS38BF	RCD SS310BF	RCD SS315BF	RCD SS320BF					
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	20	30	40	50	60	80	100	150	200	V				
Maximum RMS voltage	V <sub>RMS</sub>	14	21	28	35	42	56	70	105	140	V				
Maximum DC blocking voltage	V <sub>DC</sub>	20	30	40	50	60	80	100	150	200	V				
Maximum average forward rectified current at TL(see fig.1)	I <sub>(AV)</sub>	3.0									A				
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	80				70				A					
Maximum instantaneous forward voltage at 3.0A	V <sub>F</sub>	0.55		0.70		0.85		0.95		V					
Maximum DC reverse current T <sub>A</sub> =25°C T <sub>A</sub> =125°C at rated DC blocking voltage	I <sub>R</sub>	0.5		3.0		5.0		3.0		mA					
Typical junction capacitance (NOTE 1)	C <sub>J</sub>	450				400				pF					
Typical thermal resistance (NOTE 2)	R <sub>θJA</sub>	50.0				-55 to +125-				°C/W					
Operating junction temperature range	T <sub>J</sub>	-55 to +150								°C					
Storage temperature range	T <sub>STG</sub>									°C					

Note:1.Measured at 1MHz and applied reverse voltage of 4.0V D.C.

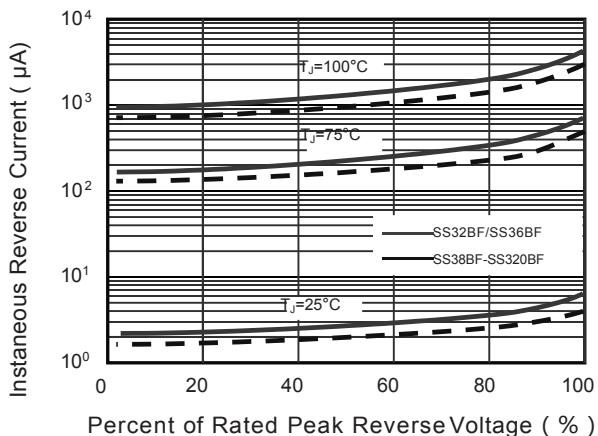
2.P.C.B. mounted with 0.2x0.2"(5.0x5.0mm) copper pad areas

## Typical Characteristics

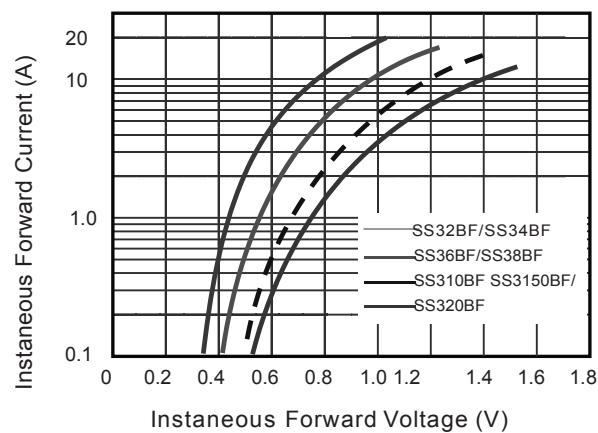
**Fig.1 Forward Current Derating Curve**



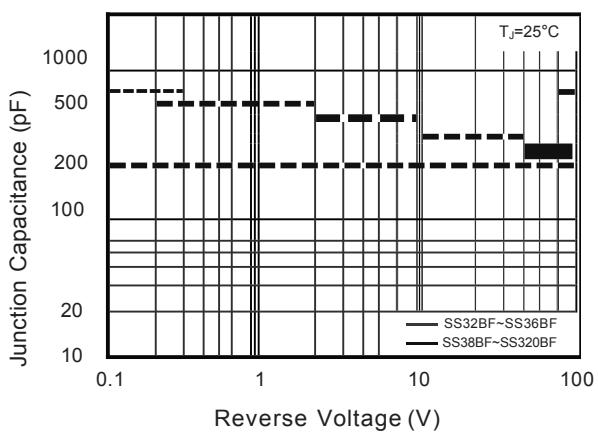
**Fig.2 Typical Reverse Characteristics**



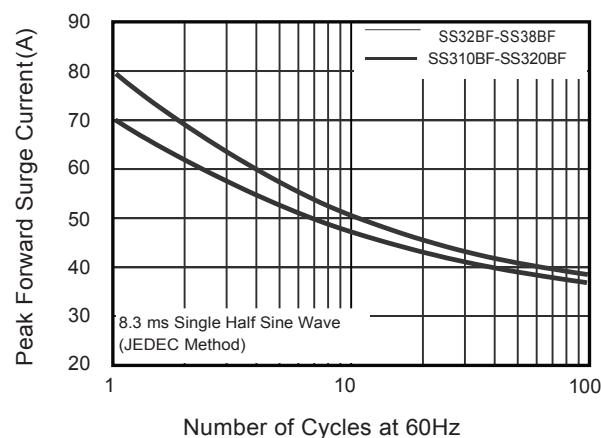
**Fig.3 Typical Forward Characteristic**



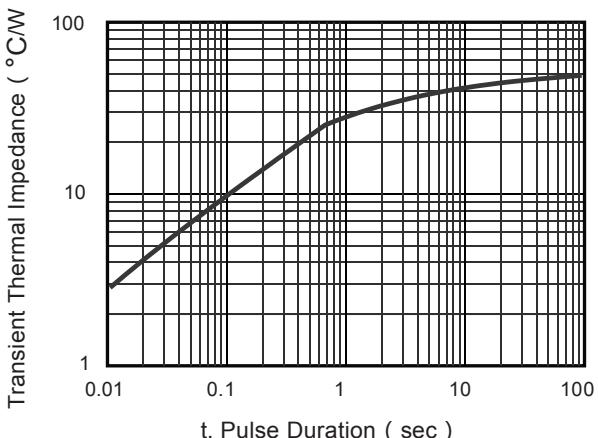
**Fig.4 Typical Junction Capacitance**



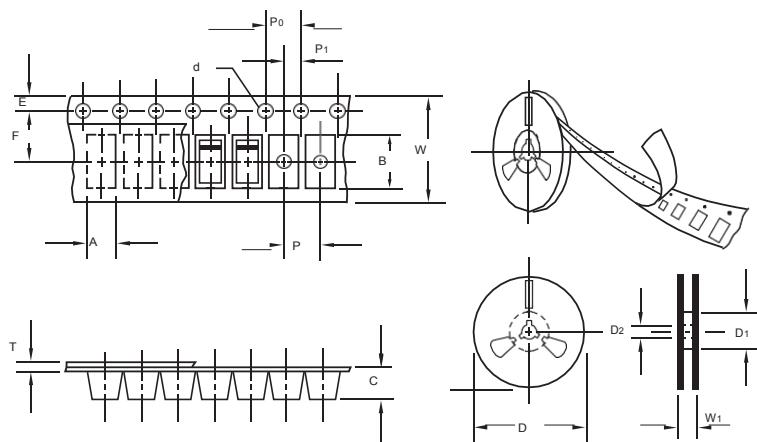
**Fig.5 Maximum Non-Repetitive Peak Forward Surge Current**



**Fig.6- Typical Transient Thermal Impedance**



The curve above is for reference only.



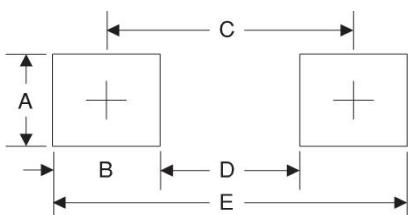
Item	Symbol	Tolerance	SMBF
Carrier width	A	0.1	3.81
Carrier length	B	0.1	5.61
Carrier depth	C	0.1	1.60
Sprocket hole	d	0.05	1.50
13" Reel outside diameter	D	2.0	330.00
13" Reel inner diameter	D <sub>1</sub>	min	50.00
Feed hole diameter	D <sub>2</sub>	0.5	13.00
Sprocket hole position	E	0.1	1.75
Punch hole position	F	0.1	5.50
Punch hole pitch	P	0.1	4.00
Sprocket hole pitch	P <sub>0</sub>	0.1	4.00
Embossment center	P <sub>1</sub>	0.1	2.00
Overall tape thickness	T	0.1	0.30
Tape width	W	0.3	12.00
Reel width	W <sub>1</sub>	1.0	12.30

Note: Devices are packed in accordance with EIA standard RS-481-A and specifications listed above.

## Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (mm)	BOX (pcs)	INNER BOX (mm)	REEL DIA, (mm)	CARTON SIZE (mm)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
SMBF	13"	5,000	4.0	10,000	190*190*41	330	365*365*360	80,000	14.0

## Suggested Pad Layout



Symbol	Unit (mm)	Unit (inch)
A	2.54	0.100
B	1.8	0.071
C	4.8	0.189
D	3.0	0.118
E	6.6	0.260